



RESEARCH ARTICLE

EFFECT OF TiO₂ AS AN ELECTRON TRANSPORT LAYER ON P3HT:IC70BA ORGANIC SOLAR CELL

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ABSTRACT

A cathode buffer layer made of TiO₂ introduced in poly(3-hexylthiophene) (P3HT): Indene-C70 Bis-Adduct (ICBA) bulk heterojunction (BHJ) solar cell. The open-circuit voltage and fill factor increase respectively to 0.62 V and 63%, due to the enhanced electron extraction by inserting a TiO₂ layer between the active layer and Al cathode. Thus, the power conversion efficiency increases from 5.8 % to 8% and the ecofriendly permanency is also much enhanced.

INTRODUCTION

Bulk heterojunction (BHJ) polymer solar cells (PSCs) have attracted considerable attentions in both academia and industry due to their low cost, flexibility and large-area fabrication features (Yip and Jen, 2012; Hoppe and Sariciftci, 2004; Cai *et al.*, 2010) compared to traditional SCs (Kosten *et al.*, 2013; Su *et al.*, 2012; Taylor, 2012). Although the power conversion efficiency (PCE) of 9.2% has been reported for single BHJ PSCs (He *et al.*, 2012), the efficiency is still lower than their inorganic semiconductor counterparts owing to the narrow absorption spectrum of polymer semiconductor (Jo *et al.*, 2013; Krebs, 2009; Ameri *et al.*, 2013). In the past few years, research efforts have focused on the developing highly efficient PSCs through various methods, such as polymer synthesis (He *et al.*, 2011; Cheng *et al.*, 2013), interfacial control (Intemann *et al.*, 2014; Zou *et al.*, 2014), tandem device (Dou *et al.*, 2012). Some light management method (Chen *et al.*, 2013; Guo *et al.*, 2014; Holman *et al.*, 2013; Lai *et al.*, 2013; Romano *et al.*, 2014; Huang *et al.*, 2013), including microcavity, photon crystal and surface Plasmon have also been applied to enhance light absorption. Since the electrical contacts between the active layer and electrodes are determinative for efficient charge transport and extraction, the interfacial control plays an

especially important role in the PCE (Po *et al.*, 2011; Chen *et al.*, 2009). The most typical OPV structure is based on the bulk heterojunction (BHJ) concept, in which a polymeric electron donor and a fullerene based electron acceptor are mixed in solution and cast into a thin film that is sandwiched between two electrodes (Dennler *et al.*, 2009). The efficiency of the BHJ is restricted by the random network that is formed through the coating and drying of the photoactive solution due to phase segregation kinetics. This leads to the formation of dead ends and isolated domains that trap charge carriers and prevent them from being extracted (Yang and Loos, 2007). Additionally, due to the low mobility of BHJ materials, there is rivalry between the dissociation and the recombination of the photo generated carriers within the thin BHJ film (Blom *et al.*, 2007). The PCE of the PSCs based on P3HT:PCBM reached over 4% (Ma *et al.*, 2005; Li *et al.*, 2005; Reyes-Reyes *et al.*, 2005) by thermal treatment (Ma *et al.*, 2005), solvent (Li *et al.*, 2005) and vapor (Zhao *et al.*, 2007) annealing, as well as mixture solvent treatment. However, further improvement of the photo voltaic performance of the PSCs based on P3HT:PCBM is limited because of the relatively small energy difference between the low estunoccupied molecular or bital (LUMO) of PCBM and the highest occupied molecular orbital (HOMO) of P3HT, which results in a lower open circuit voltage (Voc) of the P3HT:PCBM based PSCsto -0.6 V. In order to further improve device performance, anovelindene-C60 bisadduct (ICBA) (He *et al.*, 2010; Zhao *et al.*, 2010; Cheng *et al.*, 2010; Chang *et al.*, 2011) with a higher LUMO

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energy level of -3.74 eV which is higher than that of PCBM was employed as photovoltaic electron acceptor with matching up P3HT as photovoltaic electron donor. Obviously, it will result in a higher Voc and PCE of the P3HT:ICBA based PSCs than that of the P3HT:PCBM based PSCs because of the ICBA with a higher LUMO energy level. The interface modification on polymer active layer/electrodes has been comprehensively carried out for the improvement of charge injection or collection, especially due to mismatched energy level between polymer materials and metal electrodes (Zhao *et al.*, 2010; Yang *et al.*, 2008; Peumans *et al.*, 2003; Benor *et al.*, 2010; Kim *et al.*, 2010; Jönsson *et al.*, 2005). In order to modify the interface between active layer/ electrodes, many buffer layers or ultrathin layer have been reported, such as hole collecting buffer layers containing poly (3,4-ethylenedioxythiophene): poly (styrenesulfonate) (PEDOT:PSS) (Benor *et al.*, 2010; Kim *et al.*, 2010), MoO₃ (Cheng *et al.*, 2011; Zhang *et al.*, 2010), WO₃ (Yongbing, 2010), V₂O₅ (Espinosa *et al.*, 2011), and electron collecting buffer layers containing CsCO₃ (Chen *et al.*, 2008), TiO₂ (Baek *et al.*, 2009), LiF (Jönsson *et al.*, 2005; Ahlswede *et al.*, 2007; Gao *et al.*, 2010; Brabec *et al.*, 2002), Ca (Zhang *et al.*, 2010), and as to improve the device performance. However, the operation mechanism of these buffer or ultrathin layers is still in debate. Forming a tunneling junction to increase built-in electric field, an interfacial dipole layer to shift the work function of electrodes, or protect the active layer from damage is considered the underlying reason (Cai *et al.*, 2010). In this paper, we explored the enhanced performance of P3HT:ICBA based polymer solar cells using TiO₂ as an electron collecting buffer layer and PEDOT:PSS as a hole collecting buffer layer.

MATERIALS AND METHODS

OPVs were fabricated using pre-patterned ITO-coated glass substrate. Prior to the use, the substrate was cleaned in ultrasonic using 20% Decon90, deionized water, isopropanol, and acetone in the clean room, and later dried with N₂ compressor. All cleaned substrates were treated with O₂ plasma treatment for 25 min. The solution for hole transporter PEDOT:PSS solution was spin-coated at 5000 rpm for 40 s onto the cleaned substrates and annealed at 140 °C for 10 min. The photoactive layer P3HT:ICBA (1:1) w dissolved in Chlorobenzene with a concentration of 15mg/ ml was spin-coated at 1500 rpm for 35 s in the glove box and annealed at 170 °C for 45 min. Later, TiO₂ solution was spin-coated at 4000 rpm for 25 s onto the photoactive layer and annealed at 75 °C for 25 min. To complete the device, 120 nm thick Al was thermally evaporated at rate 1Å/s through a shadow mask at a base pressure of 10⁻⁶ mbar. The active area of the complete devices is 0.12 cm². Devices were tested under AM 1.5 illumination with an intensity of 100 mW/cm² simulator at room temperature. The idealized device configuration is illustrated in Fig. 1.

RESULTS AND DISCUSSION

Surface Morphology

In order to get a complete sight of comparison between both structures, an Atomic Force Microscopy (AFM) was used to examine the TiO₂ films on top of the active layer, before the back electrode deposition. The topographies are shown in

Figure 2. For pristine TiO₂ films cast from as-diluted solutions (as described in materials synthesis), the root mean square (RMS) roughness were 13.4 nm for TiO₂, while for active layer without using TiO₂ the (RMS) was 25.5 nm. Films made with TiO₂ composites show a lower roughness compared to those without it.

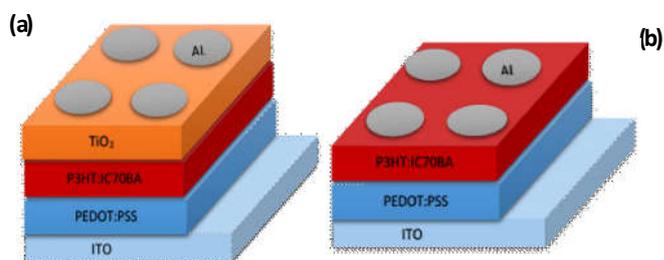


Fig. 1. Schematic diagram of P3HT:IC70BA based OBHJ solar cells (a) with TiO₂ (ETL) layer and (b) without TiO₂ (ETL) layer

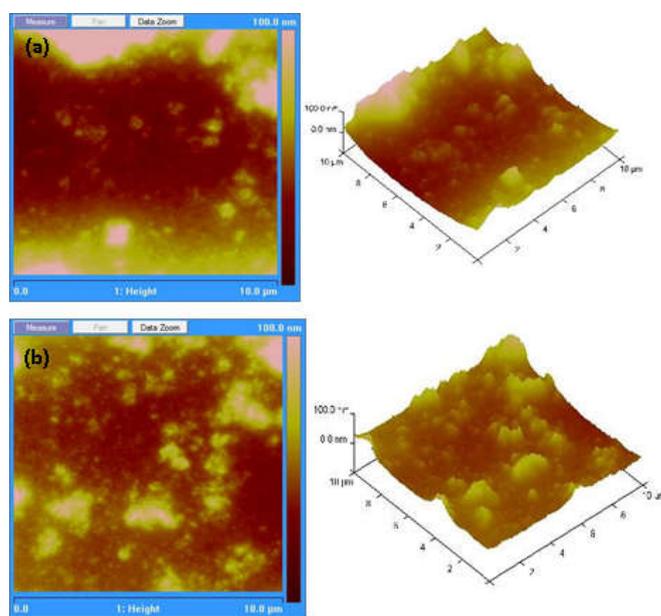


Fig. 2. AFM topography images of (a) P3HT:IC70BA on ITO/PEDOT:PSS and (b) TiO₂ on P3HT:IC70BA on ITO/PEDOT:PSS

Optical Characterization

The absorption spectra for devices of the same architecture with and without TiO₂ as ETLs are shown in Figure 3. The absorption spectra are very similar for both devices indicating there is minimum absorption from the ETLs; this suggests that it does not interfere with the ETL's secondary function as an optical spacer. (Ma *et al.*, 2002; Shrotriya *et al.*, 2006) As a result, the enhanced efficiencies observed with the TiO₂ hybrid ETLs can be ascribed primarily to their improved electrical characteristics. The optical energy gap values (E_g^{opt}) for P3HT:ICBA blends with and without TiO₂ as an electron transport layer are shown in Fig. 4. This figure reveals that the values of direct optical energy gap with TiO₂ exceeded that without TiO₂ because there is blue shift absorbance. On the other hand, the extinction coefficient and the refractive index reduced for devices using TiO₂ buffer layer as shown in Fig. 5 and 6. Table (1) exhibited the optical constants at $\lambda=700$ nm for P3HT:ICBA OBHJ devices with and without TiO₂ ETL.

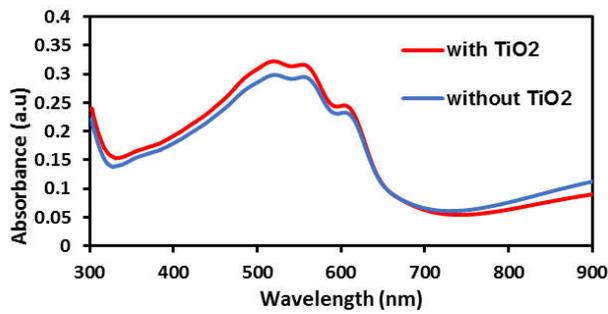


Fig. 3. UV-visible absorbance for devices with and without TiO₂ ETL

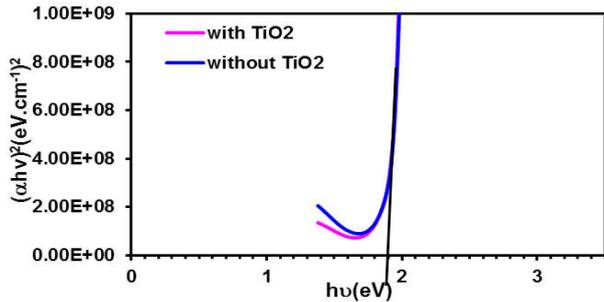


Fig. 4. Variation of $(\alpha hv)^2$ versus the photon energy ($h\nu$) for P3HT:IC70BA OBHJ devices with and without TiO₂ ETL

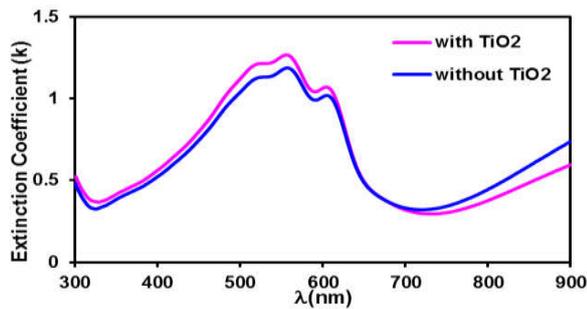


Fig. 5. Variation of extinction coefficient (k) with wavelength for P3HT:IC70BA OBHJ devices with and without TiO₂ ETL

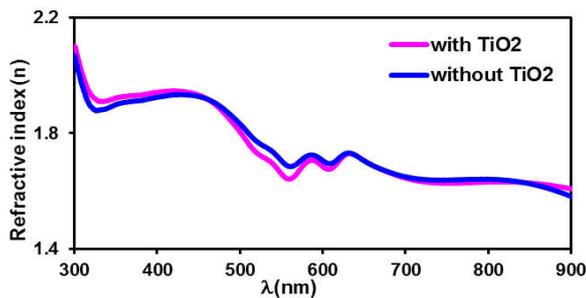


Fig. 6. Variation of Refractive Index (n) with wavelength for P3HT:IC70BA OBHJ devices with and without TiO₂ ETL

Table 1. Optical constants at $\lambda=700$ nm for P3HT:ICBA OBHJ devices with and without TiO₂ ETL

Device	A (a.u)	E _g (eV)	k	n
With TiO ₂	0.05	1.91	0.30	1.63
Without TiO ₂	0.06	1.90	0.34	1.64

Electrical Characterization

The current density–voltage (J–V) characteristics under AM 1.5G one-sun illumination condition is shown in Figure 7. Table (2) summarizes the characteristics of the device performance with and without TiO₂. A comparison of devices with an Al electrode to those with a TiO₂/Al electrode shows that the insertion of a TiO₂ layer between the active layer and the evaporated Al cathode layer leads to a significant improvement in device performance. It is known that the open circuit voltage is generally determined by the difference between the highest occupied molecular orbital (HOMO) of the donor and the lowest unoccupied molecular orbital (LUMO) of the acceptor in the case of an Ohmic contact between the active layer and the cathode (Brabec *et al.*, 2001). Thus, the increase in V_{oc} may arise from the work function of TiO₂. The V_{oc} increases from 0.36 V (for the device with no interlayer) to 0.62 V and the FF improves dramatically up to 63%. This yields to a high power conversion efficiency (PCE) of 8%. As a result, TiO₂ is a promising candidate for using as an interfacial layer, as it has been shown that inorganic oxides are quite stable to oxygen and moisture (Butterworth *et al.*, 1995). One possible reason for the increased performance of the devices with TiO₂ is the formation of a better Ohmic contact that is created by the decreased conduction band level of the TiO₂ such that the interfacial layer facilitates electron transport from the active layer to the cathode. The serial resistance is slightly decreased from 2.7–2.1 Ω, while the shunt resistance remains as high as 31.64 Ω, making it ideal for photovoltaics. The ideality factor β as shown in Table (2) is slightly increased with the insertion of buffer layer due to the increasing of the structural defects. It is believed that the TiO₂ layer can keep the hot Al electrode from diffusing into the active layer during evaporation and can offer good contact morphology between the active layer and the electrode.

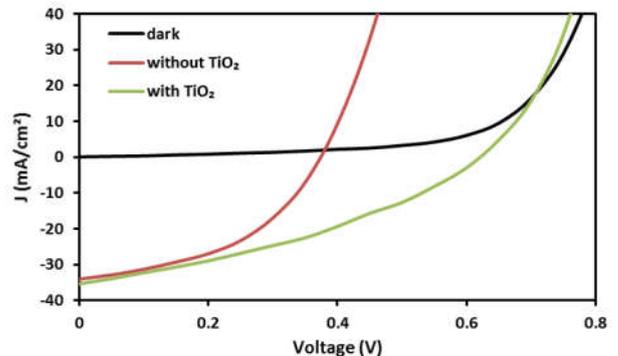


Fig.7. J-V characteristics of the OBHJ solar cells with and without TiO₂ under the illumination of 100 mW/cm² white light

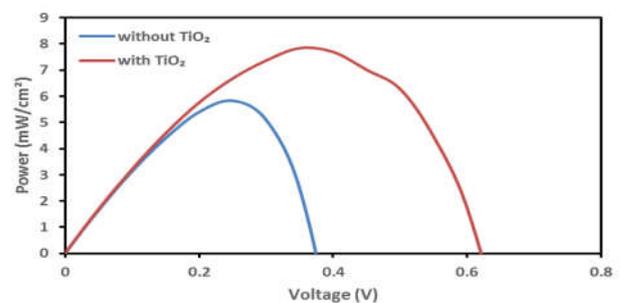


Fig.8. Power curve of P3HT:IC70BA bulk devices with and without TiO₂ interfacial layer

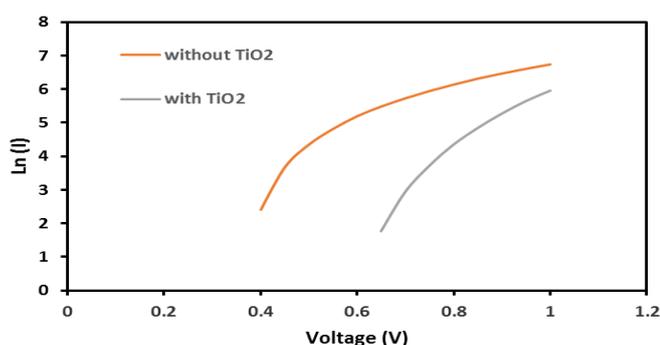


Fig. 9. Variation of $\ln(I)$ versus the bias voltage for P3HT:IC70BA OPV devices with and without TiO₂ interfacial layer

Table 2. The extracted and calculated photovoltaic parameters of the fabricated devices

Device	V _{oc} (V)	J _{sc} (mA/cm ²)	FF (%)	PCE (%)	R _s Ω	R _{sh} Ω	β
Without TiO ₂	0.36	34.08	27.6	5.83	2.7	40	1.52
With TiO ₂	0.62	35.25	63	8	2.1	31.64	1.65

Conclusion

The effect of TiO₂ interlayer on the P3HT:IC70BA BHJ solar cell was studied. Inserting TiO₂ layer between the active layer and Al cathode decreases the work function of cathode and reduces the series resistance. Therefore, Voc increases from 0.36 to 0.62 V, FF increases from 27.6% to 63% and significantly increment in PCE from 5.83% to 8%. Note that short circuit current density Jsc is almost the same. Besides of the above, the insertion of TiO₂ layer prevent the Al atoms from diffusion into the active layer and thus improve the lifetime of BHJ cells.

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